

GaAs Semiconductor Laser Diode Single Emitter Structure VE/RWL BAL DFB/DBR TPL/T

BA Laser

Version 0.90

PRELIMINARY SPECIFICATION

EYP-BAL-0980-08000-4020-CMT04-0000

General Product Information				
Product	Application			
980 nm Broad Area Laser	Material Processing			
mounted on C-Mount	Medical			

Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T _c	°C	5		40
Forward Current	I _F	А			15
Reverse Voltage	V _R	V			0
Output Power	P _{opt}	W			9

Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		30
Forward Current	I _F	А			13
Output Power	P _{opt}	W			8

Characteristics at T_{amb} 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{c}	nm	965	980	995
Spectral Width (FWHM)	Δλ	nm			6
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.4	
Output Power @ $I_F = 13 A$	Popt	W	8		
Slope Efficiency	η_d	W/A	0.6	0.7	
Threshold Current	I _{th}	А			2.5
	'th	A			2.5



Measurement Conditions / Comments

non condensing

non condensing

Stress in excess of the Absolute Maximum Ratings can cause permanent damage to the device. Operation at the Absolute Maximum Rating for extended periods of time can adversely affect the device realibility and may lead to reduced operational life.

Measurement Conditions / Comments				
measured at position A (see drawing on p. 3)				

Measurement Conditions / Comments

see images on page 4

total output measured with integrating sphere

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Characteristics at T_{amb} 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Operational Current @ $P_{opt} = 8 W$	I _{op}	А			13
Stripe Width	Ws	μm		200	
Cavity Length	L	μm		4000	
Divergence parallel (FWHM)	$\Theta_{ }$	0		10	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		30	
Spectral Mode (longitudinal)				Multi Mode	
Polarization				TE	

Measurement Conditions / Comments



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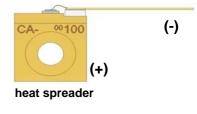
EYP-BAL-0980-08000-4020-CMT04-0000

Package Dimensions					
	Symbol	Unit	min	typ	max
Emission Plane	Ι	mm	7.05	7.20	7.35
C-Mount Thickness	d	mm		4	

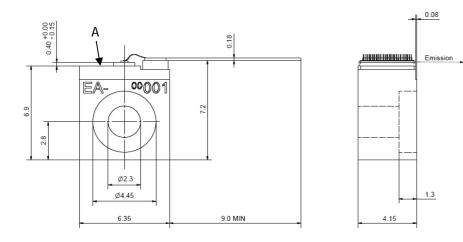
Package Pinout

Cathode (-)	Mounting Wire
Anode (+)	Housing

mounting wire



Package Drawings



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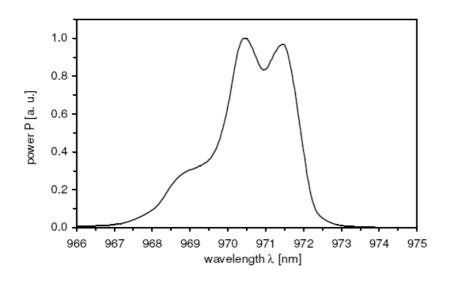
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Typical Measurement Results

Spectrum at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The BAL diode type is known to be sensitive against thermal stress. Operating at moderate temperatures on propper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase thread to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.



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